

# isc N-Channel MOSFET Transistor

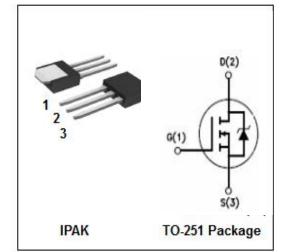
## **IRLU3105**

#### • FEATURES

- With TO-251(IPAK) packaging
- · High speed switching
- Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### APPLICATIONS

- Power supply
- DC-DC converters
- Motor control
- · Switching applications

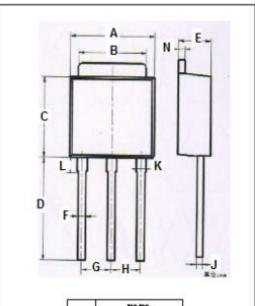


<ul> <li>ABSOLUTE</li> </ul>	<b>MAXIMUM</b>	RATINGS(T	a=25°C)
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SYMBOL	PARAMETER	VALUE	UNIT	
$V_{DSS}$	Drain-Source Voltage	55	V	
V <sub>GSS</sub>	Gate-Source Voltage	±16	۸V	
I <sub>D</sub>	Drain Current-Continuous	25	А	
I <sub>DM</sub>	Drain Current-Single Pulsed	100	А	
P <sub>D</sub>	Total Dissipation	57	W	
Tj	Operating Junction Temperature	-55~175	${\mathbb C}$	
T <sub>stg</sub>	Storage Temperature	-55~175	${\mathbb C}$	

### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	2.65	°C/W	
Rth(ch-a)	Channel-to-ambient thermal resistance	50	°C/W	



	mm		
DIM	MIN	MAX	
Α	6.40	6.48	
В	5.10	5.50	
С	5.80	6.20	
D	9.20	9.60	
E	2.20	2.40	
F	0.50	0.70	
G	2.09	2.49	
Н	2.09	2.49	
J	0.40	0.60	
K	0.70	0.90	
L	1.60	2.00	
N	0.40	0.60	

### isc N-Channel MOSFET Transistor

**IRLU3915** 

#### **ELECTRICAL CHARACTERISTICS**

 $T_{\text{C}}$ =25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 0.25mA	55			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; I <sub>D</sub> =0.25mA	1.0		3.0	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =15A		30	37	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±16V;V <sub>DS</sub> =0V			±0.2	μА
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = 55V; V <sub>GS</sub> = 0V;Tj=25℃ V <sub>DS</sub> = 44V; V <sub>GS</sub> = 0V;Tj=125℃			20 250	μА
V <sub>SDF</sub>	Diode forward voltage	I <sub>SD</sub> =15A, V <sub>GS</sub> =0V			1.3	V



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